



#### N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
60V	$2\Omega$ @ $V_{GS} = 10V$	380mA
000	$3\Omega$ @ $V_{GS} = 5V$	310mA

### **Description**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

#### **Applications**

- Motor Control
- Power Management Functions
- Backlighting

#### **Features and Benefits**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Up To 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

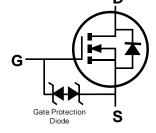
#### **Mechanical Data**

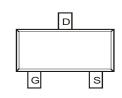
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)





SOT23





Top View

**Equivalent Circuit** 

Top View

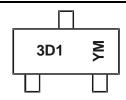
#### **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMN63D1L-7	SOT23	3000/Tape & Reel
DMN63D1L-13	SOT23	10000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



3D1 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: B = 2014) M = Month (ex: 9 = September)

Date Code Key

	/											
Year	2014	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025
Code	В	С	D	Е	F	G	Н	I	J	K	L	М
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Drain-Source Voltage		V <sub>DSS</sub>	60	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V	
			I <sub>D</sub>	380 300	mA
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	t<5s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	430 340	mA
Maximum Continuous Body Diode Forward Current	(Note 6)	Is	0.5	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	I <sub>DM</sub>	1.2	А		

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

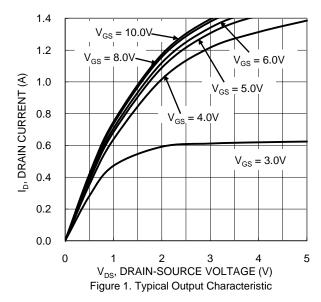
Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)		$P_{D}$	370	mW
Thermal Desigtance Junction to Ambient (Note E)	Steady State	Б	338	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<5s	$R_{\theta JA}$	292	C/VV
Total Power Dissipation (Note 6)		$P_{D}$	560	mW
Thermal Resistance, Junction to Ambient (Note 6)		D	227	°C/W
Thermal Resistance, suriction to Ambient (Note o)	t<5s	$R_{\theta JA}$	197	C/VV
Operating and Storage Temperature Range		$T_{J_i} T_{STG}$	-55 to +150	°C

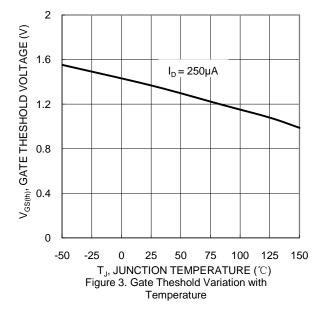
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

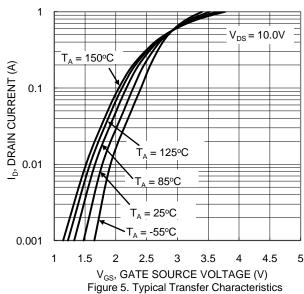
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)				ı		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	_	_	V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1.0	μΑ	V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>		_	±10	μΑ	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.0	1.6	2.5	V	$V_{DS} = 10V, I_{D} = 1mA$
Static Drain-Source On-Resistance	Paggan		_	2.0	0	$V_{GS} = 10V, I_D = 0.5A$
Static Drain-Source On-Nesistance	R <sub>DS(ON)</sub>		_	3.0	32	$V_{GS} = 5V, I_D = 0.05A$
Forward Transfer Admittance	Y <sub>fs</sub>	80	_	_	mS	$V_{DS} = 10V, I_D = 0.2A$
Diode Forward Voltage	$V_{SD}$	_	0.75	1.1	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	30	_	pF	V 25V V 2V
Output Capacitance	Coss	_	4.2	_	pF	$V_{DS} = 25V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	2.9	_	pF	1 - 1.000112
Gate Resistance	$R_{g}$	-	133	_	Ω	$f = 1MHz$ , $V_{GS} = 0V$ , $V_{DS} = 0V$
Total Gate Charge	$Q_{g}$	_	304	_	рС	\\\\ 45\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
Gate-Source Charge	Qgs	_	203	_	рC	$V_{GS} = 4.5V, V_{DS} = 10V,$ $I_{D} = 250 \text{mA}$
Gate-Drain Charge	$Q_{gd}$		84	_	рС	1D = 250111A
Turn-On Delay Time	t <sub>D(ON)</sub>	_	3.9	_	ns	
Turn-On Rise Time	t <sub>R</sub>	_	3.4	_	ns	$V_{DD} = 30V, V_{GS} = 10V,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	15.7	_	ns	$R_G = 25\Omega$ , $I_D = 200mA$
Turn-Off Fall Time	t <sub>F</sub>	_	9.9	_	ns	

- 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.
- S. Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
   Short duration pulse test used to minimize self-heating effect.
   Guaranteed by design. Not subject to product testing.









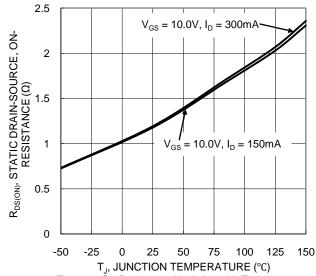
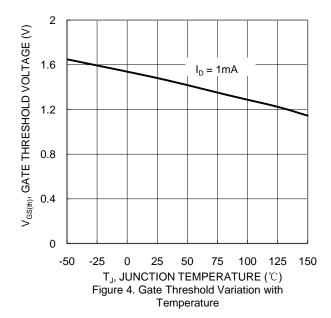


Figure 2. On-Resistance Variation with Temperature



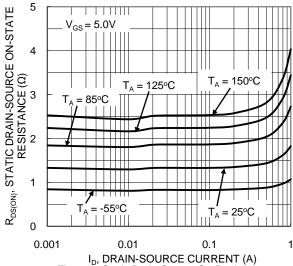
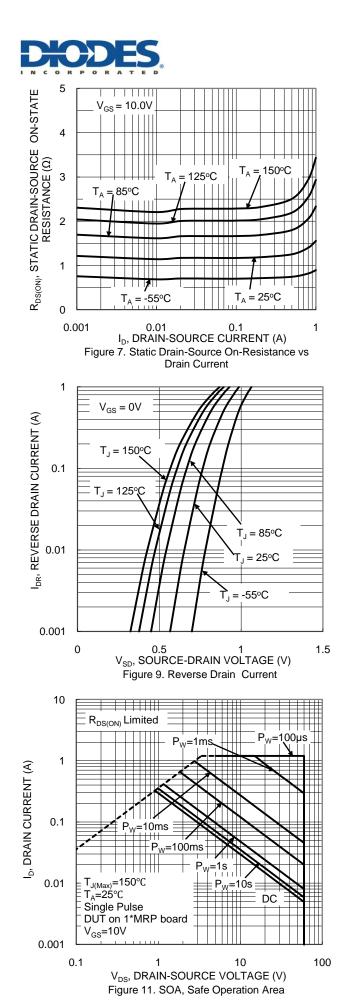
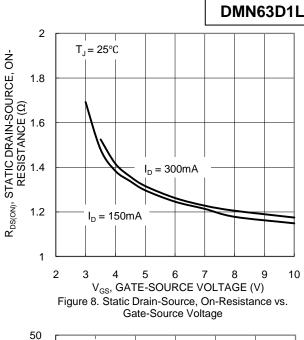
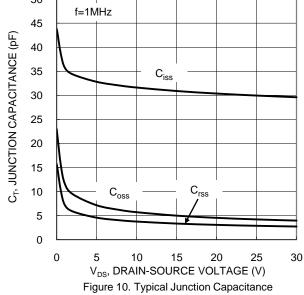


Figure 6. Static Drain-Source On-Resistance vs.

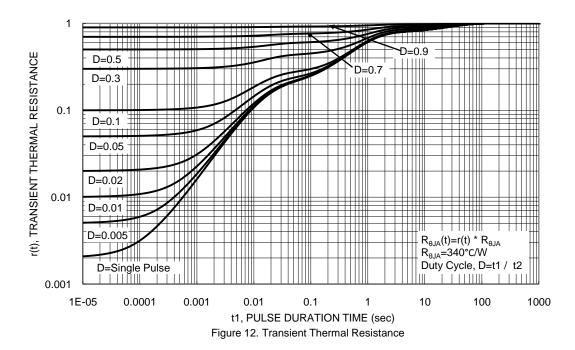
Drain Current





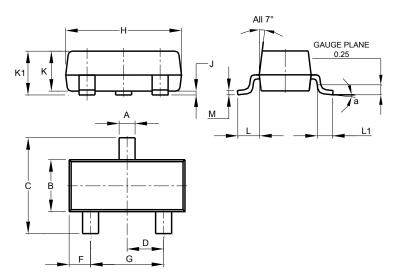






## **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

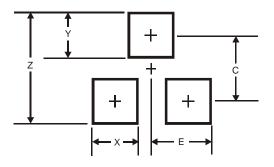


SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
C	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
7	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
M	0.085	0.150	0.110					
а	a 8°							
All	All Dimensions in mm							



#### **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.9		
Х	0.8		
Y	0.9		
С	2.0		
E	1.35		

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